Power Transistor (80V, 0.5A)

2SD1782K

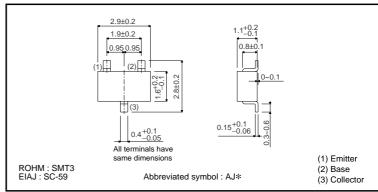
● Features

- 1) Low VcE(sat). VcE(sat) =0.2V(Typ.) (Ic / Is=0.5 A / 50mA)
- 2) High VCEO, VCEO=80V
- 3) Complements the 2SB1198K.

●Structure

Epitaxial planar type NPN silicon transistor

●External dimensions (Unit : mm)



* Denotes hre

ROHM

● Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Limits	Unit
Collector-base voltage	Vсво	80	V
Collector-emitter voltage	Vceo	80	V
Emitter-base voltage	Vево	5	V
Collector current	lc	0.5	А
Collector power dissipation	Pc	0.2	W
Junction temperature	Tj	150	°C
Storage temperature	Tstg	-55 to +150	°C

●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Collector-base breakdown voltage	ВУсво	80	_	-	V	Ic=50μA
Collector-emitter breakdown voltage	BVceo	80	_	-	V	Ic=2mA
Emitter-base breakdown voltage	ВУЕВО	5	_	-	V	I _E =50μA
Collector cutoff current	Ісво	_	_	0.5	μΑ	Vcb=50V
Emitter cutoff current	Ієво	-	-	0.5	μΑ	V _{EB} =4V
Collector-emitter saturation voltage	VCE(sat)	_	0.2	0.5	V	Ic/Iв=500mA/50mA
DC current transfer ratio	hfe	120	_	390	_	Vce=3V, Ic=100mA
Transition frequency	f⊤	_	120	_	MHz	Vce=10V, Ie= -50mA, f=100MHz
Output capacitance	Cob	_	7.5	_	pF	Vcb=10V, Ie=0A, f=1MHz

●Packaging specifications and hFE

		Package	Taping
		Code	T146
Туре	h _{FE}	Basic ordering unit (pieces)	3000
2SD1782K	QR		0

hfe values are classified as follows:

Item	Q	R
hfe	120 to 270	180 to 390

•Electrical characteristic curves

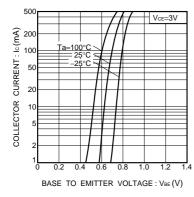


Fig.1 Grounded emitter propagation characteristics

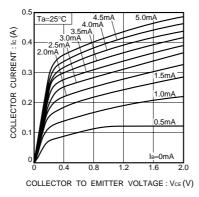


Fig.2 Grounded emitter output characteristics

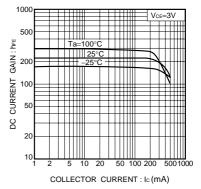
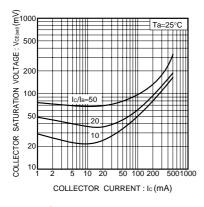
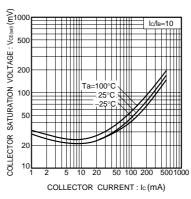


Fig.3 DC current gain vs. collector current





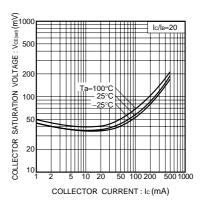


Fig.4 Collector-emitter saturation voltage vs. collector current (I)

Fig.5 Collector-emitter saturation voltage vs. collector current ($\rm II$)

Fig.6 Collector-emitter saturation voltage vs. collector current (III)

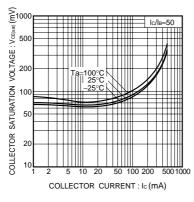


Fig.7 Collector-emitter saturation voltage vs. collector current (IV)

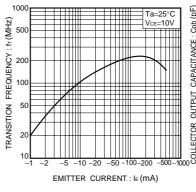


Fig.8 Gain bandwidth product vs. emitter current

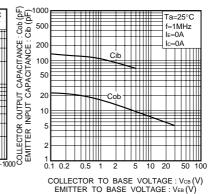


Fig.9 Collector output capacitance vs. collector-base voltage Emitter input capacitance vs. emitter-base voltage

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